



Lecture 5

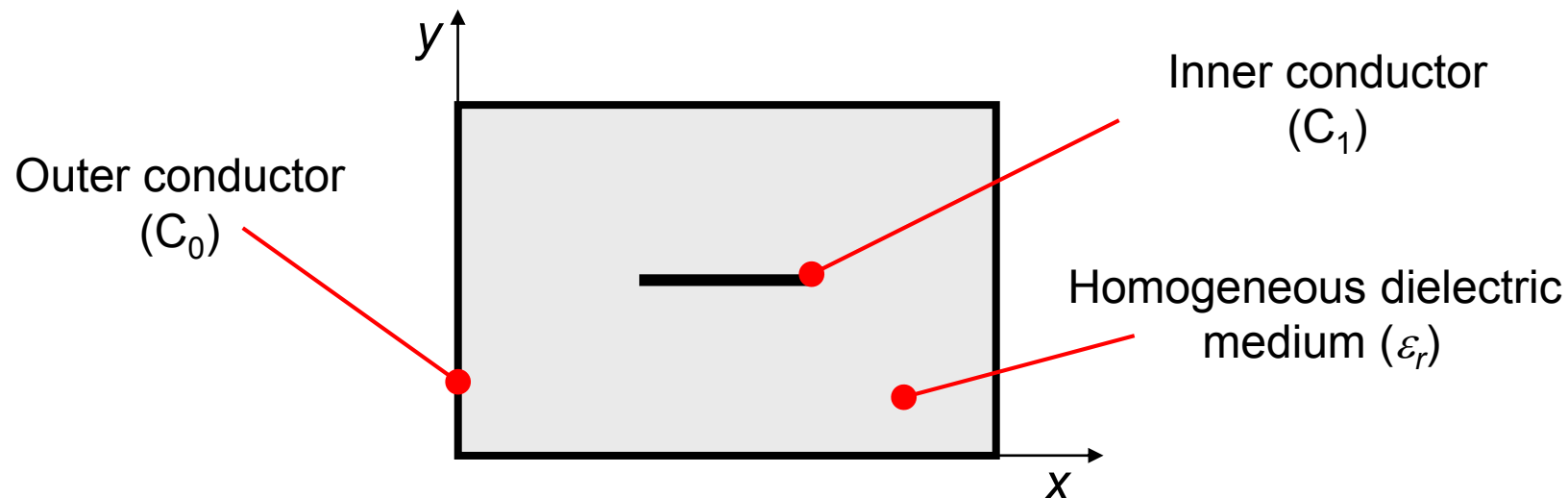
THE FDTD METHOD: EXAMPLES AND APPLICATIONS

In this lecture, the FDTD method is applied to three cases of practical interest:

1. Calculation of the TEM mode characteristics of a shielded stripline
2. Modeling of a transmission line
3. Calculation of the modes of a metallic waveguide

The achieved results represent the starting point for the numeric implementation of computer codes.

The FDTD method is applied to the calculation of the **TEM mode** characteristics of a **shielded stripline**.



The TEM mode of this structure can be determined through the solution of the **Laplace equation**, with the proper boundary condition:

$$\nabla_{\text{T}}^2 V = 0 \quad \text{in } S \quad \begin{cases} V = 0 & \text{in } C_0 \\ V = 1 & \text{in } C_1 \end{cases}$$



In a **Cartesian system**, Laplace equation can be expressed in the form:

$$\nabla_{\text{T}}^2 V = \frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} = 0$$

By applying the *central difference* method, and using **a mesh grid with size Δx e Δy** , in direction x and y , respectively, it results:

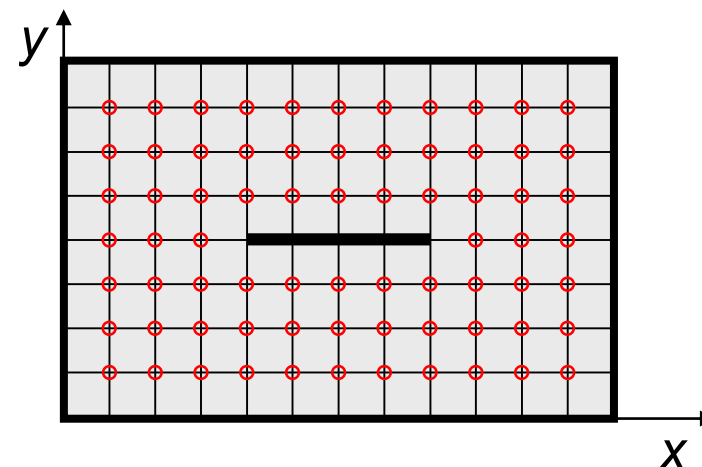
$$\frac{V(i+1, j) - 2V(i, j) + V(i-1, j)}{\Delta x^2} + \frac{V(i, j+1) - 2V(i, j) + V(i, j-1)}{\Delta y^2} = 0$$

If $\Delta x = \Delta y$, it results:

$$V(i, j) = \frac{1}{4} [V(i+1, j) + V(i-1, j) + V(i, j+1) + V(i, j-1)]$$

This equation is applied to all inner grid nodes, thus leading to a **system of equations**.

The value of function V in the boundary nodes (conductors C_0 e C_1) is determined by the boundary conditions.



The solution of the system of equations provides the **values of V in all grid nodes**.



Based on the obtained results, the **characteristic impedance** of the TEM mode can be computed.

The characteristic impedance Z_0 is defined as:

$$Z_0 = \sqrt{\frac{L}{C}}$$

where L and C represent the inductance and capacitance per unit length, respectively. The phase velocity v is given by:

$$v = \frac{1}{\sqrt{LC}}$$

By expressing L in terms of v and replacing it in the formula of Z_0 , it results:

$$Z_0 = \frac{1}{Cv}$$



As the dielectric medium is homogeneous, v results:

$$v = \frac{c}{\sqrt{\epsilon_r}}$$

Capacitance C can be computed by using the following relation:

$$C = \frac{Q}{V_d}$$

where Q represents the charge per unit length and V_d is the voltage between inner and outer conductors.

From the boundary condition it results:

$$V_d = 1$$

Charge Q is computed by applying the **Gauss law** along a closed path around the inner conductor:

$$Q = \oint_{\ell} \mathbf{D} \cdot \hat{\mathbf{n}} \, d\ell = \oint_{\ell} \varepsilon \mathbf{E} \cdot \hat{\mathbf{n}} \, d\ell =$$

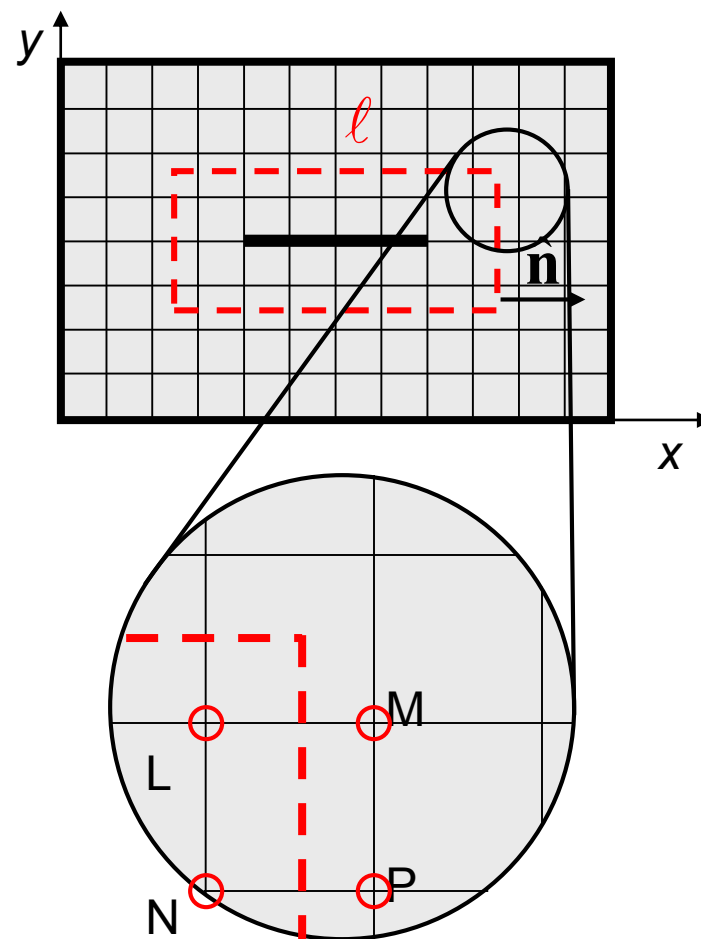
$$= - \oint_{\ell} \varepsilon \nabla V \cdot \hat{\mathbf{n}} \, d\ell = - \oint_{\ell} \varepsilon \frac{\partial V}{\partial n} \, d\ell$$

By discretizing the integral, it results:

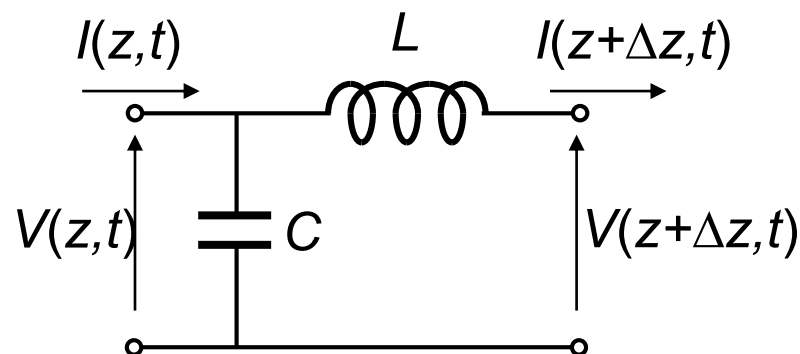
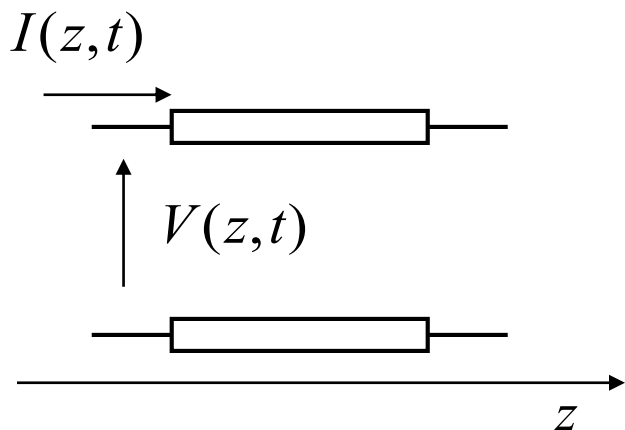
$$Q = -\varepsilon \left(\frac{V_P - V_N}{\Delta x} \Delta y + \frac{V_M - V_L}{\Delta x} \Delta y + \dots \right)$$

If $\Delta x = \Delta y$, it results:

$$Q = \varepsilon (V_N + V_L + \dots - V_P - V_M - \dots)$$



The FDTD method can be applied to the modeling of **transmission lines**.



$$V(z,t) - V(z + \Delta z, t) = L \frac{\partial I(z,t)}{\partial t} \Delta z$$

$$I(z,t) - I(z + \Delta z, t) = C \frac{\partial V(z,t)}{\partial t} \Delta z$$

$$\frac{\partial V(z,t)}{\partial z} = -L \frac{\partial I(z,t)}{\partial t}$$

$$\frac{\partial I(z,t)}{\partial z} = -C \frac{\partial V(z,t)}{\partial t}$$



The differential equations are discretized by using the *central difference* method, with space grid size Δz and time step Δt .

From the **first equation** it results:

$$\left. \frac{\partial V(z, t)}{\partial z} \right|_{z=(i-1/2)\Delta z, t=n\Delta t} = \frac{V(i, n) - V(i-1, n)}{\Delta z}$$
$$\left. \frac{\partial I(z, t)}{\partial t} \right|_{z=(i-1/2)\Delta z, t=n\Delta t} = \frac{I(i-1/2, n+1/2) - I(i-1/2, n-1/2)}{\Delta t}$$

By replacing in the first equation, it results:

$$\frac{V(i, n) - V(i-1, n)}{\Delta z} = -L \frac{I(i-1/2, n+1/2) - I(i-1/2, n-1/2)}{\Delta t}$$

After re-ordering with respect to the most recent time value:

$$I(i-1/2, n+1/2) = I(i-1/2, n-1/2) - \frac{\Delta t}{L} \frac{V(i, n) - V(i-1, n)}{\Delta z}$$



Similarly, from the **second equation** it results:

$$\left. \frac{\partial I(z,t)}{\partial z} \right|_{z=(i-1)\Delta z, t=(n+1/2)\Delta t} = \frac{I(i-1/2, n+1/2) - I(i-3/2, n+1/2)}{\Delta z}$$
$$\left. \frac{\partial V(z,t)}{\partial t} \right|_{z=(i-1)\Delta z, t=(n+1/2)\Delta t} = \frac{V(i-1, n+1) - V(i-1, n)}{\Delta t}$$

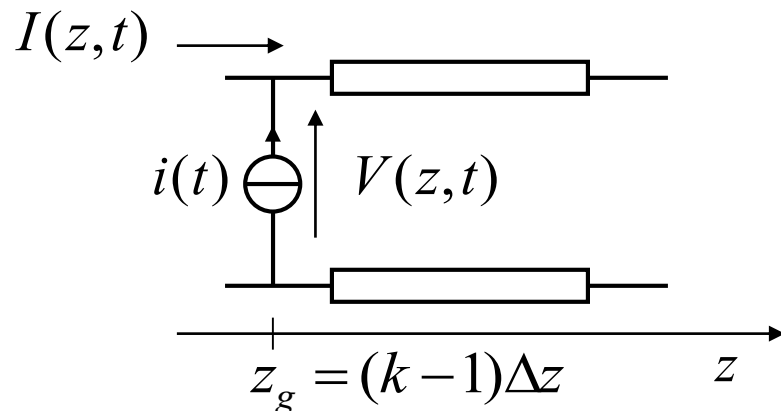
By replacing in the second equation, it results:

$$\frac{I(i-1/2, n+1/2) - I(i-3/2, n+1/2)}{\Delta z} = -C \frac{V(i-1, n+1) - V(i-1, n)}{\Delta t}$$

After re-ordering with respect to the most recent time value:

$$V(i-1, n+1) = V(i-1, n) - \frac{\Delta t}{C} \frac{I(i-1/2, n+1/2) - I(i-3/2, n+1/2)}{\Delta z}$$

If there is a **current source** at section z_g , the equations are modified in the following way:



$$\frac{\partial V(z,t)}{\partial z} = -L \frac{\partial I(z,t)}{\partial t}$$

$$\frac{\partial I(z,t)}{\partial z} = -C \frac{\partial V(z,t)}{\partial t} + \delta(z - z_g) i(t)$$

The discretized equations become:

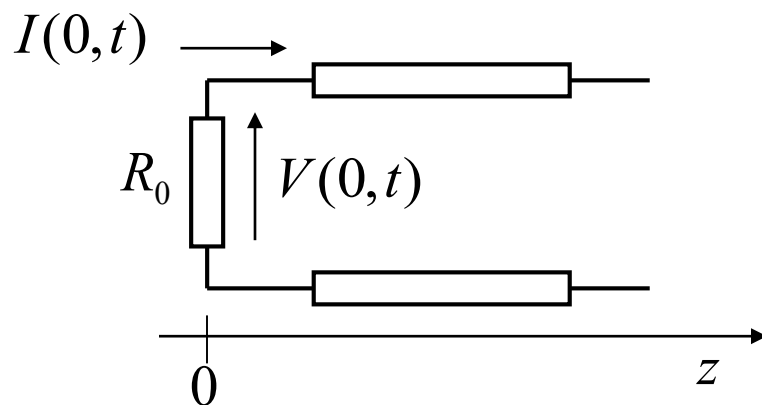
$$I(k - 1/2, n + 1/2) = I(k - 1/2, n - 1/2) - \frac{\Delta t}{L} \frac{V(k, n) - V(k - 1, n)}{\Delta z}$$

$$V(k - 1, n + 1) = V(k - 1, n) + \frac{\Delta t}{C} \frac{I(k - 1/2, n + 1/2) - I(k - 3/2, n + 1/2)}{\Delta z} + \frac{\Delta t}{C} i(n + 1/2)$$

The **boundary conditions** are represented by the load resistances, at sections $z=0$ and $z=L$.

A. Case $z=0$

If we consider the load impedance R_0 at section $z=0$, it results:



$$V(0,t) = -R_0 I(0,t)$$

The second equation, discretized at $z=0$, needs to be modified.

The space derivative of the current in section $z=0$ is:

$$\left. \frac{\partial I(z,t)}{\partial z} \right|_{z=0, t=(n+1/2)\Delta t} = \frac{I(1/2, n+1/2) - I(0, n+1/2)}{\Delta z / 2}$$

By exploiting the boundary condition (Ohm law), it results:

$$\left. \frac{\partial I(z,t)}{\partial z} \right|_{z=0, t=(n+1/2)\Delta t} = \frac{I(1/2, n+1/2) + V(0, n+1/2) / R_0}{\Delta z / 2}$$

As the voltage is not computed at time step $(n+1/2)\Delta t$, the interpolated value is used:

$$\left. \frac{\partial I(z,t)}{\partial z} \right|_{z=0, t=(n+1/2)\Delta t} = \frac{I(1/2, n+1/2) + [V(0, n) + V(0, n+1)] / 2R_0}{\Delta z / 2}$$



The time derivative of voltage is:

$$\left. \frac{\partial V(z, t)}{\partial t} \right|_{z=0, t=(n+1/2)\Delta t} = \frac{V(0, n+1) - V(0, n)}{\Delta t}$$

By replacing in the second equation, it results:

$$\frac{2I(1/2, n+1/2) + [V(0, n) + V(0, n+1)]/R_0}{\Delta z} = -C \frac{V(0, n+1) - V(0, n)}{\Delta t}$$

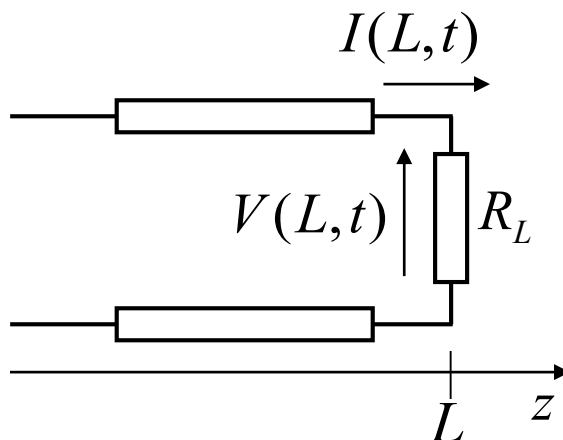
After re-ordering with respect to the most recent time value:

$$V(0, n+1) = \frac{R_0 C \Delta z - \Delta t}{R_0 C \Delta z + \Delta t} V(0, n) - \frac{2R_0 \Delta t}{R_0 C \Delta z + \Delta t} I(1/2, n+1/2)$$



B. Case $z=L$

If we consider the load impedance R_L at section $z=L$, it results:



$$V(L,t) = R_L I(L,t)$$

Also in this case, **the second equation, discretized at $z=L$, needs to be modified.** It results:

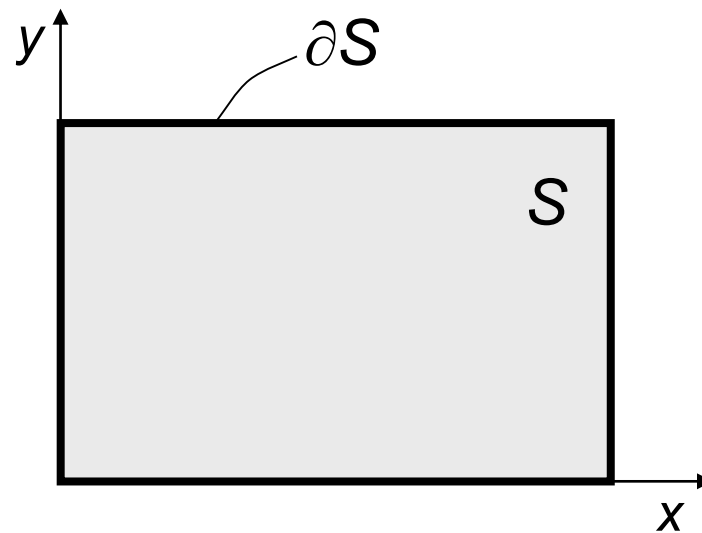
$$V(N_z, n+1) = \frac{R_L C \Delta z - \Delta t}{R_L C \Delta z + \Delta t} V(N_z, n) + \frac{2R_L \Delta t}{R_L C \Delta z + \Delta t} I(N_z - 1/2, n + 1/2)$$

The **calculation of the modes of a metallic waveguide** can be implemented by using a finite difference method.

The waveguide modes can be expressed in terms of scalar potentials, which are the eigen-solutions of the **Helmholtz equation** with proper boundary conditions:

$$\begin{cases} \nabla_{\text{T}}^2 \Phi - k^2 \Phi = 0 & \text{in } S \\ \Phi = 0 & \text{su } \partial S \end{cases} \quad (\text{TM modes})$$

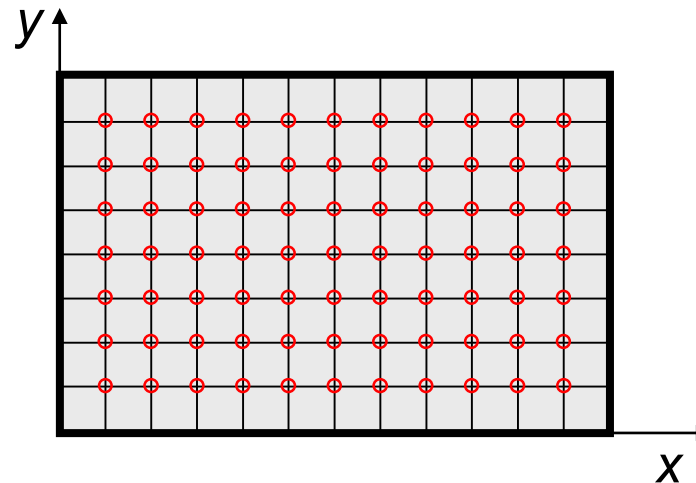
$$\begin{cases} \nabla_{\text{T}}^2 \Phi - k^2 \Phi = 0 & \text{in } S \\ d\Phi/dn = 0 & \text{su } \partial S \end{cases} \quad (\text{TE modes})$$



The Helmholtz equation is discretized by adopting the *central difference* method. By using a space grid size $\Delta x = \Delta y = h$, it results:

$$\Phi(i+1, j) + \Phi(i-1, j) + \Phi(i, j+1) + \Phi(i, j-1) - (4 - h^2 k^2) \Phi(i, j) = 0$$

NOTE: this equation is applied to **all inner nodes**.



For nodes located on the boundary, TM and TE cases require different treatments.

A. TM modes

In the case of TM modes, the Dirichlet condition is applied ($\Phi=0$ on ∂S).

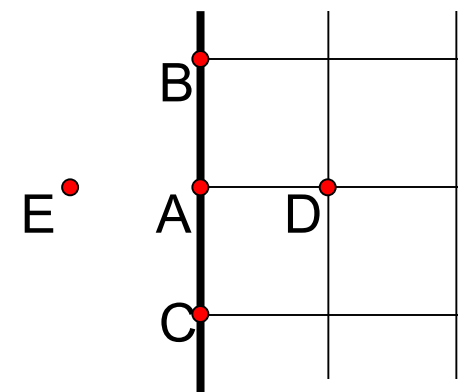
B. Modi TE

In the case of TE modes, the Neumann condition is applied ($d\Phi/dn=0$ on ∂S). In the case shown in the figure, it results:

$$\frac{\partial\Phi}{\partial n} = 0 \quad \Rightarrow \quad \Phi_D = \Phi_E$$

It finally leads to:

$$\Phi_B + \Phi_C + 2\Phi_D - (4 - h^2 k^2)\Phi_A = 0$$





By applying the discretized Helmholtz equation and the boundary conditions to all grid nodes, a **system of N equations** is obtained, in the form:

$$\boxed{(A - \lambda I)\Phi = 0} \quad \text{or} \quad A\Phi = \lambda\Phi$$

where A is an $N \times N$ matrix and I is the identity matrix with size $N \times N$.

The solution of the systems yields:

eigen-vectors Φ (related to the values of modal voltage in the grid nodes)

eigen-values λ (related to the modal cutoff wave-numbers).

NOTE: The solution of this problem can be based on a direct method: by imposing $|A - \lambda I| = 0$, a polynomial function in λ is obtained, whose zeros provide the eigen-values of the problem.